Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.095 inches

Overall Diameter:

Between 0.318 inches and 0.380 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.431 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

450.0 working peak reverse voltage

Current Rating Per Characteristic:

12.00 amperes forward current, average absolute and 120.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Test Data Document:

97942-583r510 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0